## FEATURES

- SN74CBT3253C Functionally Identical to Industry-Standard '3253 Function
- Undershoot Protection for Off-Isolation on A and B Ports up to -2 V
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance ( $r_{\text {on }}$ ) Characteristics ( $\mathrm{r}_{\text {on }}=3 \Omega$ Typical)
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion

D, DB, DBQ, OR PW PACKAGE
(TOP VIEW)

( $\mathrm{C}_{\text {io(OFF) }}=5.5 \mathrm{pF}$ Typical)

- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption ( $\mathrm{I}_{\mathrm{cc}}=3 \mu \mathrm{~A}$ Max)
- $\mathrm{V}_{\mathrm{cc}}$ Operating Range From 4 V to 5.5 V
- Data I/Os Support 0 to 5-V Signaling Levels ( $0.8 \mathrm{~V}, 1.2 \mathrm{~V}, 1.5 \mathrm{~V}, 1.8 \mathrm{~V}, 2.5 \mathrm{~V}, 3.3 \mathrm{~V}, 5 \mathrm{~V}$ )
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- $\mathrm{I}_{\text {off }}$ Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
- 2000-V Human-Body Model (A114-B, Class II)
- 1000-V Charged-Device Model (C101)
- Supports $I^{2} \mathrm{C}$ Bus Expansion
- Supports Both Digital and Analog

Applications: USB Interface, Bus Isolation, Low-Distortion Signal Gating


## DESCRIPTION/ORDERING INFORMATION

The SN74CBT3253C is a high-speed TTL-compatible FET multiplexer/demultiplexer with low ON-state resistance $\left(r_{\text {on }}\right)$, allowing for minimal propagation delay. Active Undershoot-Protection Circuitry on the $A$ and $B$ ports of the SN74CBT3253C provides protection for undershoot up to -2 V by sensing an undershoot event and ensuring that the switch remains in the proper OFF state.

The SN74CBT3253C is organized as two 1-of-4 multiplexer/demultiplexers with separate output-enable (1 $\overline{\mathrm{OE}}$, $2 \overline{\mathrm{OE}}$ ) inputs. The select (S0, S1) inputs control the data path of each multiplexer/demultiplexer. When $\overline{\mathrm{OE}}$ is low, the associated multiplexer/demultiplexer is enabled, and the A port is connected to the B port, allowing bidirectional data flow between ports. When $\overline{O E}$ is high, the associated multiplexer/demultiplexer is disabled, and a high-impedance state exists between the $A$ and $B$ ports.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

## DESCRIPTION/ORDERING INFORMATION (CONTINUED)

This device is fully specified for partial-power-down applications using $\mathrm{I}_{\text {off. }}$. The $\mathrm{I}_{\text {off }}$ feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.
To ensure the high-impedance state during power up or power down, $\overline{\mathrm{OE}}$ should be tied to $\mathrm{V}_{\mathrm{CC}}$ through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

| TA | PACKAGE ${ }^{(1)}$ |  | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
| :---: | :---: | :---: | :---: | :---: |
| $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ | QFN - RGY | Reel of 1000 | SN74CBT3253CRGYR | CU253C |
|  | SOIC - D | Tube of 40 | SN74CBT3253CD | CBT3253C |
|  |  | Reel of 2500 | SN74CBT3253CDR |  |
|  | SSOP - DB | Tube of 80 | SN74CBT3253CDB | CU253C |
|  |  | Reel of 2000 | SN74CBT3253CDBR |  |
|  | SSOP (QSOP) - DBQ | Reel of 2500 | SN74CBT3253CDBQR | CU253C |
|  | TSSOP - PW | Tube of 90 | SN74CBT3253CPW | CU253C |
|  |  | Reel of 2000 | SN74CBT3253CPWR |  |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE
(each multiplexer/demultiplexer)

| INPUTS |  |  | ${ }_{\text {INPUT/OUTPUT }}$ | FUNCTION |
| :---: | :---: | :---: | :---: | :---: |
| OE | S1 | so |  |  |
| L | L | L | B1 | A port = B1 port |
| L | L | H | B2 | A port = B2 port |
| L | H | L | B3 | $A$ port $=B 3$ port |
| L | H | H | B4 | A port = B4 port |
| H | X | X | X | Disconnect |


(1) EN is the internal enable signal applied to the switch.

5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION
SCDS123B-JULY 2003-REVISED JANUARY 2007

## Absolute Maximum Ratings ${ }^{(1)}$

over operating free-air temperature range (unless otherwise noted)

|  |  |  | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage |  | -0.5 | 7 | V |
| $\mathrm{V}_{\text {IN }}$ | Control input voltage range ${ }^{(2)(3)}$ |  | -0.5 | 7 | V |
| $\mathrm{V}_{1 / \mathrm{O}}$ | Switch I/O voltage range ${ }^{(2)(3)(4)}$ |  | -0.5 | 7 | V |
| $\mathrm{I}_{1 \times}$ | Control input clamp current | $\mathrm{V}_{\text {IN }}<0$ |  | -50 | mA |
| $\mathrm{I}_{\text {/OK }}$ | I/O port clamp current | $\mathrm{V}_{1 / \mathrm{O}}<0$ |  | -50 | mA |
| $\mathrm{I}_{1 / \mathrm{O}}$ | ON-state switch current ${ }^{(5)}$ |  |  | $\pm 128$ | mA |
|  | Continuous current through $\mathrm{V}_{\text {CC }}$ or GND terminals |  |  | $\pm 100$ | mA |
|  |  | D package ${ }^{(6)}$ |  | 73 |  |
|  |  | DB package ${ }^{(6)}$ |  | 82 |  |
| $\theta_{\mathrm{JA}}$ | Package thermal impedance | DBQ package ${ }^{(6)}$ |  | 90 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  | PW package ${ }^{(6)}$ |  | 108 |  |
|  |  | RGY package ${ }^{(7)}$ |  | 39 |  |
| $\mathrm{T}_{\text {stg }}$ | Storage temperature range |  | -65 | 150 | ${ }^{\circ} \mathrm{C}$ |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages are with respect to ground unless otherwise specified.
(3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(4) $V_{I}$ and $V_{O}$ are used to denote specific conditions for $V_{1 / O}$.
(5) $I_{1}$ and $I_{O}$ are used to denote specific conditions for $l_{I / O}$.
(6) The package thermal impedance is calculated in accordance with JESD 51-7.
(7) The package thermal impedance is calculated in accordance with JESD 51-5.

## Recommended Operating Conditions ${ }^{(1)}$

|  |  | MIN | MAX |
| :--- | :--- | ---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Unpply voltage | 4 | 5.5 |
| $\mathrm{~V}_{\mathrm{IH}}$ | High-level control input voltage | 2 | 5.5 |
| $\mathrm{~V}_{\mathrm{IL}}$ | Low-level control input voltage | V |  |
| $\mathrm{V}_{\mathrm{IO}}$ | Data input/output voltage | 0 | 0.8 |
| $\mathrm{~T}_{\mathrm{A}}$ | Operating free-air temperature | 0 | 5.5 |

(1) All unused control inputs of the device must be held at $\mathrm{V}_{\mathrm{CC}}$ or $G N D$ to ensure proper device operation. Refer to the Tl application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## Electrical Characteristics ${ }^{(1)}$

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  |  | MIN TYP ${ }^{(2)}$ | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IK}}$ | Control inputs | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$, | $\mathrm{I}_{\text {IN }}=-18 \mathrm{~mA}$ |  |  | -1.8 | V |
| $\mathrm{V}_{\text {IKU }}$ | Data inputs | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$, | $0 \mathrm{~mA}>\mathrm{I}_{1} \geq-50 \mathrm{~mA}$, $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}}$ or GND, | Switch OFF |  | -2 | V |
| $\mathrm{I}_{\mathrm{N}}$ | Control inputs | $\mathrm{V}_{C C}=5.5 \mathrm{~V}$, | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {CC }}$ or GND |  |  | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{l}_{\mathrm{O}}{ }^{(3)}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\begin{aligned} & \mathrm{V}_{\mathrm{O}}=0 \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{~V}_{1}=0, \end{aligned}$ | Switch OFF, $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}}$ or GND |  | $\pm 10$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {off }}$ |  | $\mathrm{V}_{\mathrm{CC}}=0$, | $\mathrm{V}_{\mathrm{O}}=0$ to 5.5 V , | $V_{1}=0$ |  | 10 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{CC}}$ |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | $\begin{aligned} & \mathrm{I}_{\mathrm{I} O}=0, \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \text { or } \mathrm{GND}, \end{aligned}$ | Switch ON or OFF |  | 3 | $\mu \mathrm{A}$ |
| $\Delta \mathrm{lCC}^{(4)}$ | Control inputs | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | One input at 3.4 V , | Other inputs at $\mathrm{V}_{\mathrm{CC}}$ or GND |  | 2.5 | mA |
| $\mathrm{C}_{\text {in }}$ | Control inputs | $\mathrm{V}_{\text {IN }}=3 \mathrm{~V}$ or 0 |  |  | 3.5 |  | pF |
| $\mathrm{C}_{\mathrm{io} \text { (OFF) }}$ | A port | $\mathrm{V}_{I / O}=3 \mathrm{~V}$ or 0 , | Switch OFF, | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {CC }}$ or GND | 14 |  | pF |
|  | B port |  |  |  | 5.5 |  |  |
| $\mathrm{C}_{\text {io(ON) }}$ |  | $\mathrm{V}_{I O}=3 \mathrm{~V}$ or 0 , | Switch ON, | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {CC }}$ or GND | 22 |  | pF |
| $\mathrm{r}_{\text {on }}{ }^{(5)}$ |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=4 \mathrm{~V}, \\ & \mathrm{TYP} \text { at } \mathrm{V}_{\mathrm{CC}}=4 \mathrm{~V} \end{aligned}$ | $\mathrm{V}_{\mathrm{I}}=2.4 \mathrm{~V}$, | $\mathrm{l}_{\mathrm{O}}=-15 \mathrm{~mA}$ | 8 | 12 | $\Omega$ |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | $\mathrm{V}_{1}=0$ | $\mathrm{I}_{\mathrm{O}}=64 \mathrm{~mA}$ | 3 | 6 |  |
|  |  | $\mathrm{I}_{\mathrm{O}}=30 \mathrm{~mA}$ |  | 3 | 6 |  |
|  |  | $\mathrm{V}_{1}=2.4 \mathrm{~V}$, | $\mathrm{I}_{\mathrm{O}}=-15 \mathrm{~mA}$ | 5 | 10 |  |

(1) $\mathrm{V}_{\mathbb{I N}}$ and $\mathrm{I}_{\mathbb{N}}$ refer to control inputs. $\mathrm{V}_{\mathrm{I}}, \mathrm{V}_{\mathrm{O}}, \mathrm{I}_{\mathrm{I}}$, and $\mathrm{I}_{0}$ refer to data pins.
(2) All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ (unless otherwise noted), $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
(3) For I/O ports, the parameter $\mathrm{I}_{\mathrm{Oz}}$ includes the input leakage current.
(4) This is the increase in supply current for each input that is at the specified voltage level, rather than $V_{C C}$ or GND
(5) Measured by the voltage drop between the $A$ and $B$ terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two ( $A$ or $B$ ) terminals.

## Switching Characteristics

over recommended operating free-air temperature range, $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ (unless otherwise noted) (see Figure 3)

| PARAMETER | FROM (INPUT) | $\begin{gathered} \text { TO } \\ \text { (OUTPUT) } \end{gathered}$ | $\mathrm{V}_{\mathrm{CC}}=4 \mathrm{~V}$ | $\begin{gathered} \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \\ \pm 0.5 \mathrm{~V} \end{gathered}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN MAX | MIN | MAX |  |
| $\mathrm{t}_{\mathrm{pd}}{ }^{(1)}$ | A or B | $B$ or $A$ | 0.24 |  | 0.15 | ns |
| $\mathrm{t}_{\mathrm{pd}(\mathrm{s})}$ | S | A | 5.9 | 1.5 | 5.4 | ns |
| $t_{\text {en }}$ | S | B | 6.2 | 1.5 | 5.8 | ns |
|  | $\overline{\text { OE }}$ | A or B | 5.7 | 1.5 | 5.3 |  |
| $\mathrm{t}_{\text {dis }}$ | S | B | 6.2 | 1.5 | 5.8 | ns |
|  | $\overline{\mathrm{OE}}$ | A or B | 5.7 | 1.5 | 5.3 |  |

(1) The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

## Undershoot Characteristics

See Figure 1] and Figure 2

| PARAMETER | TEST CONDITIONS | MIN | TYP(1) | MAX | UNIT |
| :---: | :---: | :---: | ---: | ---: | :---: |
| $\mathrm{V}_{\text {OUTU }}$ | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$, | Switch OFF, | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}}$ or GND | 2 | $\mathrm{~V}_{\mathrm{OH}}-0.3$ |

(1) All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ (unless otherwise noted), $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.


Figure 1. Device Test Setup


Figure 2. Transient Input Voltage $\left(\mathrm{V}_{\mathrm{I}}\right)$ and Output Voltage (V ${ }_{\text {OUTU }}$ ) Waveforms (Switch OFF)

## PARAMETER MEASUREMENT INFORMATION



| TEST | $\mathrm{V}_{\mathrm{CC}}$ | S 1 | $\mathrm{R}_{\mathrm{L}}$ | $\mathrm{V}_{\mathbf{I}}$ | $\mathrm{C}_{\mathrm{L}}$ | $\mathrm{V}_{\Delta}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{pd}(\mathrm{s})}$ | $5 \mathrm{~V} \pm 0.5 \mathrm{~V}$ | Open | $500 \Omega$ | $\mathrm{~V}_{\mathrm{CC}}$ or GND | 50 pF |  |
|  | 4 V | Open | $500 \Omega$ | $\mathrm{~V}_{\mathrm{CC}}$ or GND | 50 pF |  |
| $\mathrm{t}_{\mathrm{PLZ}} / \mathrm{t}_{\mathrm{PZL}}$ | $5 \mathrm{~V} \pm 0.5 \mathrm{~V}$ | 7 V | $500 \Omega$ | GND | 50 pF | 0.3 V |
|  | 4 V | 7 V | $500 \Omega$ | GND | 50 pF | 0.3 V |
| $\mathrm{t}_{\text {PHZ }} / \mathrm{t}_{\mathrm{PZH}}$ | $5 \mathrm{~V} \pm 0.5 \mathrm{~V}$ | Open | $500 \Omega$ | $\mathrm{~V}_{\mathrm{CC}}$ | 50 pF | 0.3 V |
|  | 4 V | Open | $500 \Omega$ | $\mathrm{~V}_{\mathrm{CC}}$ | 50 pF | 0.3 V |



VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES ( $\left.\mathrm{t}_{\mathrm{pd}(\mathrm{s})}\right)$


VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
NOTES: A. $C_{L}$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{r}} \leq 2.5 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}} \leq 2.5 \mathrm{~ns}$.
D. The outputs are measured one at a time, with one transition per measurement.
E. $t_{p L Z}$ and $t_{P H Z}$ are the same as $t_{\text {dis }}$.
F. $t_{P Z L}$ and $t_{P Z H}$ are the same as $t_{\text {en }}$.
G. $t_{P L H}$ and $t_{P H L}$ are the same as $t_{p d(s)}$. The $t_{p d}$ propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
H. All parameters and waveforms are not applicable to all devices.

Figure 3. Test Circuit and Voltage Waveforms

## PACKAGING INFORMATION

| Orderable Device | Status <br> (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <br> (2) | Lead finish/ Ball material <br> (6) | MSL Peak Temp <br> (3) | Op Temp ( ${ }^{\circ} \mathrm{C}$ ) | Device Marking <br> (4/5) | Samples |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SN74CBT3253CD | ACTIVE | SOIC | D | 16 | 40 | RoHS \& Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CBT3253C | Samples |
| SN74CBT3253CDBQR | ACTIVE | SSOP | DBQ | 16 | 2500 | RoHS \& Green | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | CU253C | Samples |
| SN74CBT3253CDBR | ACTIVE | SSOP | DB | 16 | 2000 | RoHS \& Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CU253C | Samples |
| SN74CBT3253CDR | ACTIVE | SOIC | D | 16 | 2500 | RoHS \& Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CBT3253C | Samples |
| SN74CBT3253CDRE4 | ACTIVE | SOIC | D | 16 | 2500 | RoHS \& Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CBT3253C | Samples |
| SN74CBT3253CDRG4 | ACTIVE | SOIC | D | 16 | 2500 | RoHS \& Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CBT3253C | Samples |
| SN74CBT3253CPW | ACTIVE | TSSOP | PW | 16 | 90 | RoHS \& Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CU253C | Samples |
| SN74CBT3253CPWR | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS \& Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | CU253C | Samples |
| SN74CBT3253CRGYR | ACTIVE | VQFN | RGY | 16 | 3000 | RoHS \& Green | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | CU253C | Samples |

${ }^{(1)}$ The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device
${ }^{(2)}$ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed $0.1 \%$ by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.
${ }^{(3)}$ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
${ }^{(4)}$ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device
${ }^{(5)}$ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
${ }^{(6)}$ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width

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## TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package <br> Type | Package <br> Drawing | Pins | SPQ | Reel <br> Diameter <br> $(\mathbf{m m})$ | Reel <br> Width <br> $\mathbf{W 1 ( m m )}$ | A0 <br> $(\mathbf{m m})$ | B0 <br> $(\mathbf{m m})$ | K0 <br> $(\mathbf{m m})$ | P1 <br> $(\mathbf{m m})$ | $\mathbf{W}$ <br> $(\mathbf{m m})$ | Pin1 <br> Quadrant |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SN74CBT3253CDBQR | SSOP | DBQ | 16 | 2500 | 330.0 | 12.5 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| SN74CBT3253CDBR | SSOP | DB | 16 | 2000 | 330.0 | 16.4 | 8.35 | 6.6 | 2.4 | 12.0 | 16.0 | Q1 |
| SN74CBT3253CDR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| SN74CBT3253CPWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| SN74CBT3253CRGYR | VQFN | RGY | 16 | 3000 | 330.0 | 12.4 | 3.8 | 4.3 | 1.5 | 8.0 | 12.0 | Q1 |

PACKAGE MATERIALS INFORMATION
InSTRUMENTS

*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SN74CBT3253CDBQR | SSOP | DBQ | 16 | 2500 | 340.5 | 338.1 | 20.6 |
| SN74CBT3253CDBR | SSOP | DB | 16 | 2000 | 853.0 | 449.0 | 35.0 |
| SN74CBT3253CDR | SOIC | D | 16 | 2500 | 340.5 | 336.1 | 32.0 |
| SN74CBT3253CPWR | TSSOP | PW | 16 | 2000 | 367.0 | 367.0 | 35.0 |
| SN74CBT3253CRGYR | VQFN | RGY | 16 | 3000 | 367.0 | 367.0 | 35.0 |

D (R-PDSO-G16)


NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.

C Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $0.006(0,15)$ each side.
D Body width does not include interlead flash. Interlead flash shall not exceed $0.017(0,43)$ each side.
E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16)


NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC-7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.


NOTES: (continued)
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.


SOLDER PASTE EXAMPLE BASED ON 0.125 mm THICK STENCIL SCALE: 10X

NOTES: (continued)
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.


| DIM PINS ** | $\mathbf{1 4}$ | $\mathbf{1 6}$ | $\mathbf{2 0}$ | $\mathbf{2 4}$ | $\mathbf{2 8}$ | $\mathbf{3 0}$ | $\mathbf{3 8}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| A MAX | 6,50 | 6,50 | 7,50 | 8,50 | 10,50 | 10,50 | 12,90 |
| A MIN | 5,90 | 5,90 | 6,90 | 7,90 | 9,90 | 9,90 | 12,30 |

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-150


## NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 inch, per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MO-137, variation AB.


SOLDER MASK DETAILS

## NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.


SOLDER PASTE EXAMPLE
BASED ON . 005 INCH [0.127 MM] THICK STENCIL
SCALE:8X

NOTES: (continued)
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

RGY (R-PVQFN-N16) PLASTIC QUAD FLATPACK NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).
For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.


Bottom View

Exposed Thermal Pad Dimensions

NOTE: All linear dimensions are in millimeters


NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC-7351 is recommended for alternate designs.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http: //www.ti.com>.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

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